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Vishay Semiconductor/Diodes Division VS-403CNQ100PBF

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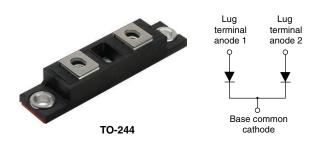


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VS-403CNQ100PbF

Vishay Semiconductors

High Performance Schottky Rectifier, 400 A



400 A

100 V

TO-244

Two diodes common cathode

PRODUCT SUMMARY

I_{F(AV)}

 V_R

Package

Circuit

FEATURES

- 175 °C T_J operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- UL approved file E222165
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-403CNQ... center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	400	A				
V _{RRM}		100	V				
I _{FSM}	t _p = 5 μs sine	25 500	A				
V _F	200 A _{pk} , T _J = 125 °C (per leg)	0.69	V				
TJ	Range	-55 to 175	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-403CNQ100PbF	UNITS			
Maximum DC reverse voltage	V _R	100	V			
Maximum working peak reverse voltage	V _{RWM}	100	v			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward per leg			E0.0 duty cycle at $T = 1.41.$	200			
current See fig. 5	per device	I _{F(AV)}	50 % duty cycle at T _C = 141 °C	400	- A		
Maximum peak one cycle non-repetitive surge current per leg See fig. 7		I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated		25 500	
			10 ms sine or 6 ms rect. pulse	V _{RRM} applied		3300	
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 13 A, L = 0.2 mH		15	mJ	
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		1	А	

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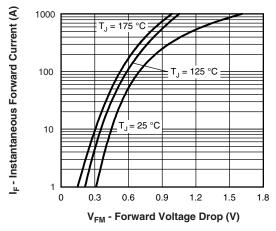
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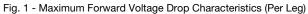
ELECTRICAL SPECIFICATIONS							
PARAMETER SYMBOL		TEST COND	VALUES	UNITS			
		200 A	T ₁ = 25 °C	0.84	V		
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	400 A	1j=25 0	1.07			
See fig. 1		200 A	$T_{i} = T_{i}$ maximum	0.69			
		400 A	ij = ij maximum	0.82			
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	6	mA		
See fig. 2		T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	80			
Maximum junction capacitance per leg	CT	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		5500	pF		
Typical series inductance per leg L _S		From top of terminal hole to mounting plane		5.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

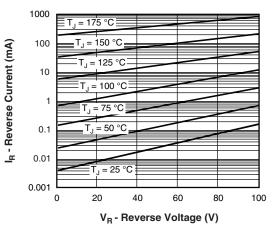
Note

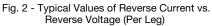
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}	-55	-	175	°C	
Thermal resistance, junction to case per leg	р	-	-	0.19	°C/W	
Thermal resistance, junction to case per module	– R _{thJC}	-	-	0.095		
Thermal resistance, case to heatsink	R _{thCS}	-	0.10	-		
Weight		-	68	-	g	
Weight		-	2.4	-	oz.	
Mounting torque		35.4 (4)		53.1 (6)		
Mounting torque center hole		30 (3.4)		40 (4.6)	lbf ⋅ in (N ⋅ m)	
Terminal torque		30 (3.4)	-	44.2 (5)	(
Vertical pull		-	-	80	lbf in	
2" lever pull		-	-	35	lbf ⋅ in	









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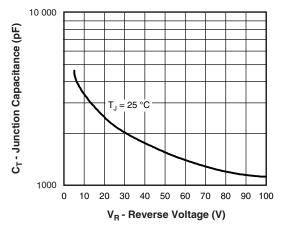


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

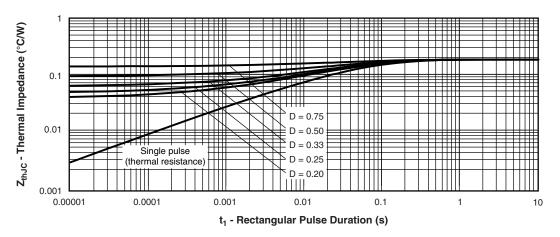
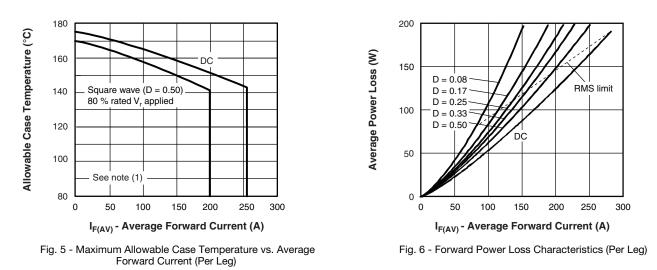


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)



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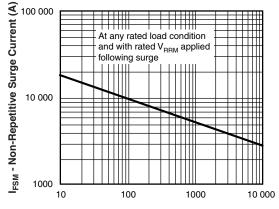




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 t_p - Square Wave Pulse Duration (µs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

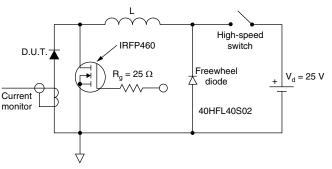


Fig. 8 - Unclamped Inductive Test Circuit

Note

 $^{(1)}$ Formula used: $T_{C} = T_{J} - (Pd + Pd_{REV}) \times R_{thJC};$ Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_{R}$ (1 - D); I_{R} at V_{R1} = 80 % rated V_{R}

ORDERING INFORMATION TABLE

Device code	VS-	40	3	С	N	Q	100	PbF
		2	3	4	5	6	7	8
	 Vishay Semiconductors product Average current rating (x 10) Product silicon identification 							
	4 - C = Circuit configuration							
	5 - N = Not isolated							
	6 - Q = Schottky rectifier diode							
	7 - Voltage rating (100 = 100 V)							
	8 - Lead (Pb)-free							

LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95021							

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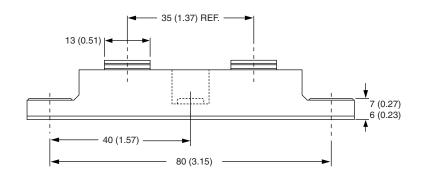
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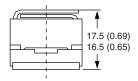
Outline Dimensions

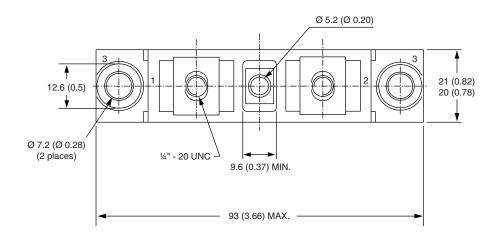
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TO-244

DIMENSIONS in millimeters (inches)











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